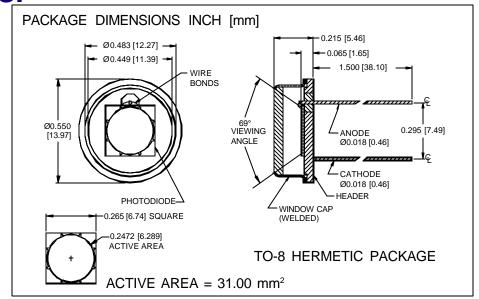
PHOTONIC DETECTORS INC.

Silicon Photodiode, Blue Enhanced Photovoltaic Type PDB-V108





FEATURES

- Low noise
- Blue enhanced
- High shunt resistance
- High response

DESCRIPTION

The **PDB-V108** is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for low noise photovoltaic applications. Packaged in a hermetic TO-8 metal can with a flat window.

APPLICATIONS

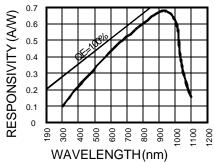
- Laser sensor
- Instrumentation
- Industrial controls
- Colorimetry

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V _{BR}	Reverse Voltage		75	V
T _{STG}	Storage Temperature	-55	+150	⊙C
To	Operating Temperature Range	-40	+125	⊙C
Ts	Soldering Temperature*		+240	∘C
IL	Light Current		500	mA

^{*1/16} inch from case for 3 secs max

SPECTRALRESPONSE



ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Isc	Short Circuit Current	H = 100 fc, 2850 K	375	430		m A
ΙD	Dark Current	H = 0, V _R = 10 V		250	800	pA
RsH	Shunt Resistance	H = 0, V _R = 10 mV	.2	1		GΩ
TC Rsh	RsH Temp. Coefficient	$H = 0$, $V_R = 10 \text{ mV}$		-8		%/℃
Cı	Junction Capacitance	$H = 0$, $V_R = 0 V^{**}$		2500		рF
λrange	Spectral Application Range	Spot Scan	350		1100	nm
λр	Spectral Response - Peak	Spot Scan		950		nm
VBR	Breakdown Voltage	I = 10 mA	30	40		V
NEP	Noise Equivalent Power	V _R = 10 mV @ Peak		5x10 ⁻¹⁴		W/ √ Hz
tr	Response Time	$RL = 1 K\Omega V_R = 0 V$		950		nS